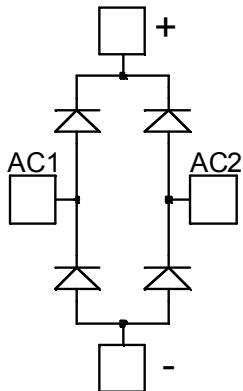
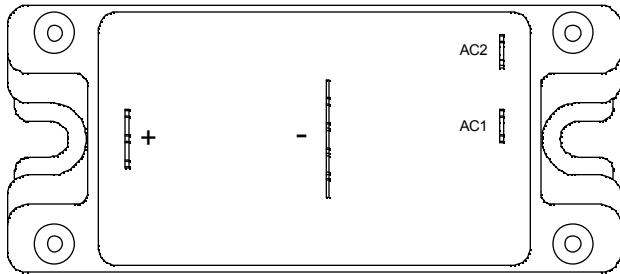


**Diode Full Bridge  
Power Module**
**V<sub>RRM</sub> = 1200V**  
**I<sub>C</sub> = 100A @ T<sub>c</sub> = 60°C**

**Application**

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

**Features**

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
  - Symmetrical design
  - Lead frames for power connections
- High level of integration


**Benefits**

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant

**Absolute maximum ratings**

Symbol	Parameter	Max ratings		Unit
V <sub>R</sub>	Maximum DC reverse Voltage		1200	V
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			
I <sub>F(AV)</sub>	Maximum Average Forward Current	Duty cycle = 50%	T <sub>C</sub> = 25°C T <sub>C</sub> = 60°C	120 100
I <sub>F(RMS)</sub>	RMS Forward Current	Duty cycle = 50%	T <sub>C</sub> = 45°C	135
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current	8.3ms	T <sub>C</sub> = 45°C	500

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

### Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_F$	Diode Forward Voltage	$I_F = 100\text{A}$		2.4	3		V
		$I_F = 150\text{A}$		2.7			
		$I_F = 100\text{A}$	$T_j = 125^\circ\text{C}$		1.8		
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 1200\text{V}$	$T_j = 25^\circ\text{C}$			100	$\mu\text{A}$
			$T_j = 125^\circ\text{C}$			500	
$C_T$	Junction Capacitance	$V_R = 1200\text{V}$			110		pF

### Dynamic Characteristics

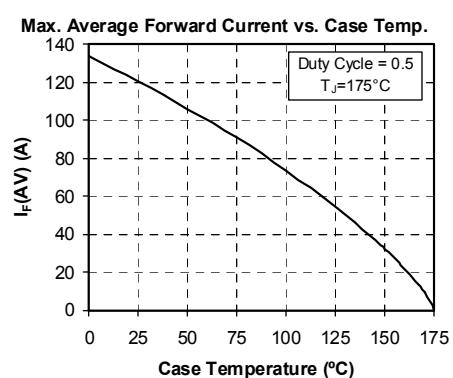
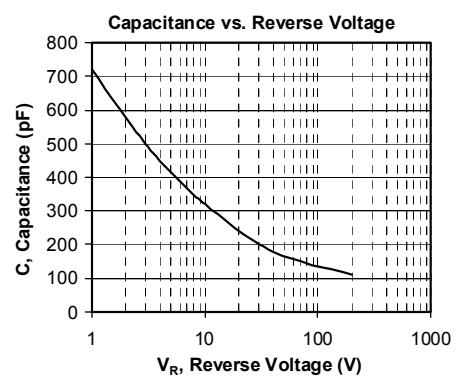
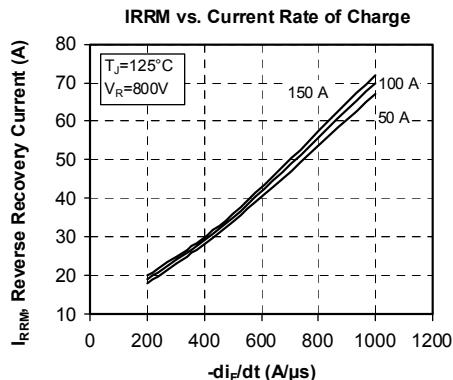
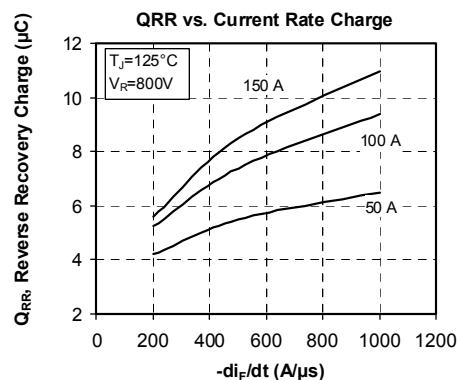
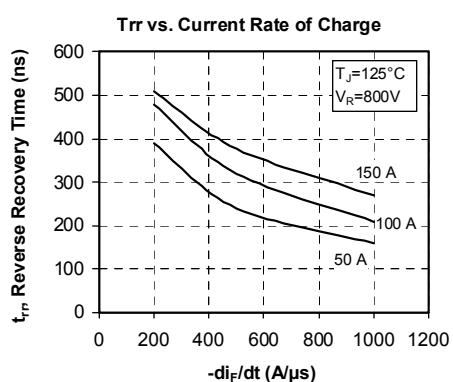
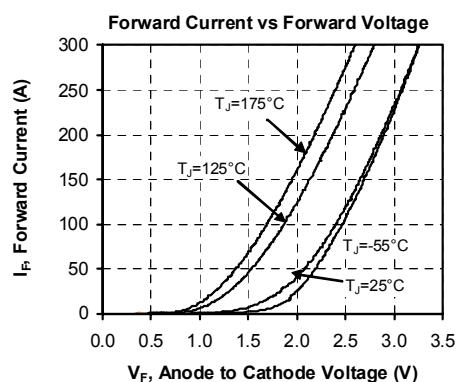
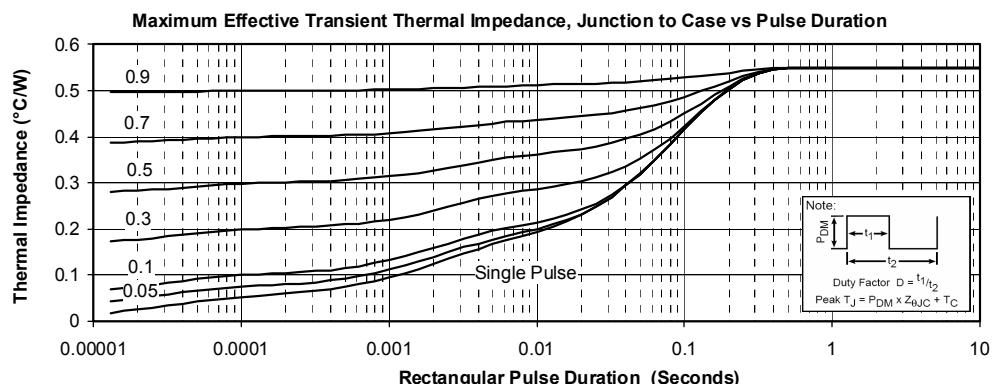
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
$t_{rr}$	Reverse Recovery Time	$I_F=1\text{A}, V_R=30\text{V}$ $di/dt = 100\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$		45		ns	
$t_{rr}$	Reverse Recovery Time	$I_F = 100\text{A}$ $V_R = 800\text{V}$ $di/dt = 200\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$		385		ns	
			$T_j = 125^\circ\text{C}$		480			
$Q_{rr}$	Reverse Recovery Charge		$T_j = 25^\circ\text{C}$		1055		nC	
			$T_j = 125^\circ\text{C}$		5240			
$I_{RRM}$	Reverse Recovery Current		$T_j = 25^\circ\text{C}$		6		A	
			$T_j = 125^\circ\text{C}$		19			
$t_{rr}$	Reverse Recovery Time	$I_F = 100\text{A}$ $V_R = 800\text{V}$ $di/dt=1000\text{A}/\mu\text{s}$	$T_j = 125^\circ\text{C}$		210		ns	
$Q_{rr}$	Reverse Recovery Charge				9.4		$\mu\text{C}$	
$I_{RRM}$	Reverse Recovery Current				70		A	

### Thermal and package characteristics

Symbol	Characteristic	Min	Typ	Max	Unit	
$R_{thJC}$	Junction to Case Thermal Resistance			0.55	$^\circ\text{C}/\text{W}$	
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, $I_{isol} < 1\text{mA}$ , 50/60Hz	2500			V	
$T_J$	Operating junction temperature range	-40		175	$^\circ\text{C}$	
$T_{STG}$	Storage Temperature Range	-40		125		
$T_C$	Operating Case Temperature	-40		100		
Torque	Mounting torque	To Heatsink	M5	2.5	4.7	N.m
Wt	Package Weight			160	g	

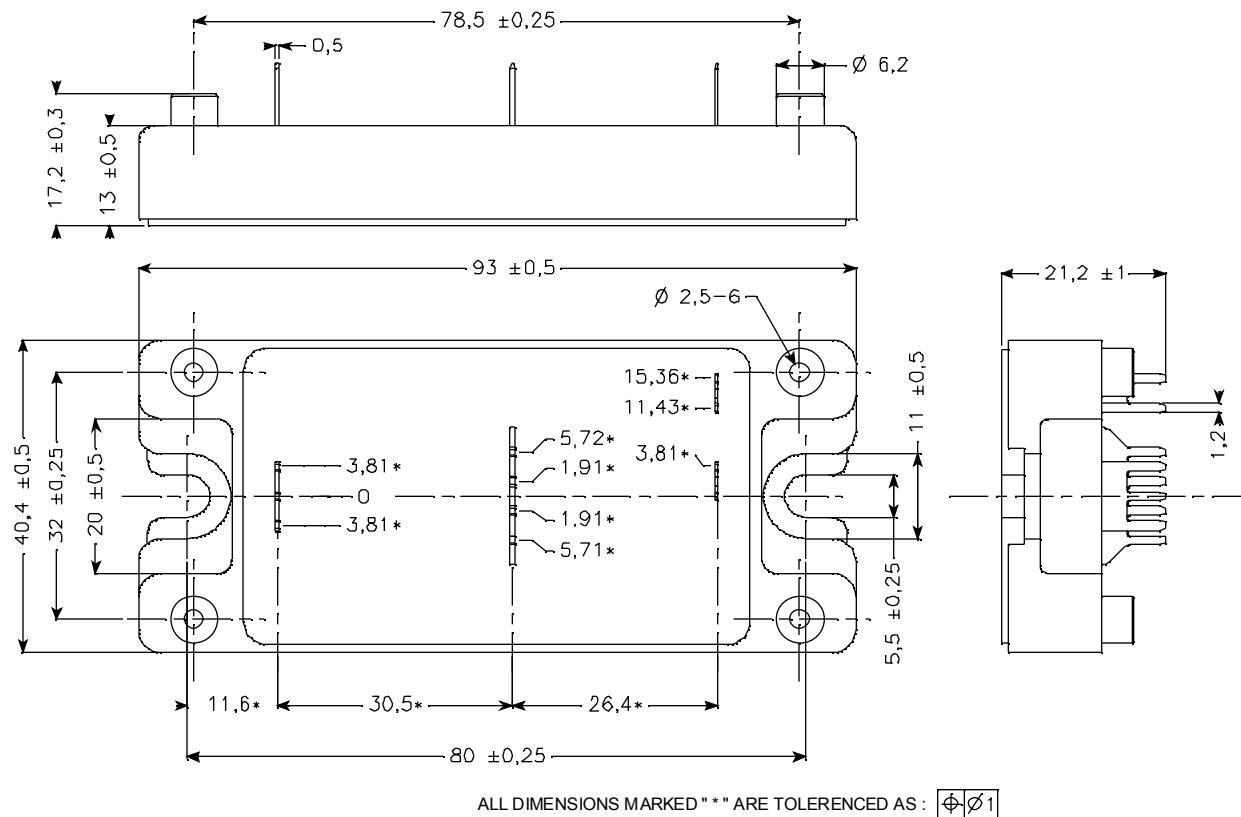


## Typical Performance Curve





## **SP4 Package outline (dimensions in mm)**



**Microsemi reserves the right to change, without notice, the specifications and information contained herein**

Microsem's products are covered by one or more of U.S patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522  
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